



Photoluminescence from Single-Crystal and Thin-Film Cs₂TiBr₆

- Single-crystal and thin-film Cs₂TiBr₆ exhibit broad PL that can be deconvolved into multiple peaks
- Largest photoluminescence peak at ~2.13 eV is above the bulk 1.8–1.9 eV band gap
- Above E_a PL observed previously in other inorganic perovskites CsPbCl₃ and CsPbBr₃ and attributed to an exciton bound to a higher-lying defect state within the conduction band [3]
- Near band gap emission also observed
- Lower energy band in thin film spectra is likely defect- and grain-boundary related
- Radiative carrier lifetime is shorter in a thin film due to recombination at defects and grain boundaries
- Single crystal: emission linear in excitation fluence
- Thin film: emission intensity shows saturation as available states fill

References & Acknowledgements

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